

Title (en)
METHOD FOR FABRICATING THIN FILM SEMICONDUCTOR DEVICES

Title (de)
VERFAHREN ZUR HERSTELLUNG VON DÜNNSCHICHTHALBLEITERBAUELEMENTEN

Title (fr)
PROCEDES POUR FABRIQUER DES DISPOSITIFS SEMI-CONDUCTEURS A FILM MINCE

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Abstract (en)
[origin: EP1024523A1] The present invention is related to a method for fabricating thin film semiconductor devices on a reusable substrate. Examples of such devices are for instance solar cells, light emitting diodes and power devices. The invented method allows for simple and cheap processing techniques like for instance screen printing and electroless etching to be successfully applied in combination with thin film semiconductor devices of only a few μm thickness using very cheap supports such as plastic films. The whole process is executed on a high quality substrate which is compatible with all high temperature treatments such as e.g. diffusion and thermal oxidation. Semiconductor thin films are grown on a porous layer formed on the surface of the reusable substrate. After being attached to a cheap second substrate, i.e. the support, the completed thin film semiconductor devices are lifted off from this comparably expensive substrate at the end of the process by a wet etching of the porous layer.
<IMAGE>

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